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OCT 19 2005

I hereby certify that the attached PTO form 1449 (3 pages) with 4 cited references (31 pages), Information Disclosure Statement (1 page) are submitted to the U.S. Patent and Trademark Office via facsimile number 571-273-8300 on the date shown below. (Total 35 pages).


Li Mei Vermilya

Date: October 19, 2005

PATENT APPLICATION
Docket No. 9898-314
Client No. SS-20035-US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Won-Jun Lee, et al.

Serial No. 10/763,356 Examiner: Pham, Thanhha S.

Filed: January 23, 2004 Art Unit: 2813

Conformation No. 7097

For: ETCHING METHOD FOR MANUFACTURING
SEMICONDUCTOR DEVICEMail Stop Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450INFORMATION DISCLOSURE STATEMENT

Sir:

This Information Disclosure Statement is submitted:

- ☐ under 37 CFR 1.97 (b); or
(Within three months of filing national application; or date of entry of International application; or before mailing date of first office action on the merits; or before the mailing of a first Office Action after the filing of a request for continued examination under §1.114; whichever occurs last)

- ☒ under 37 CFR 1.97 (c) together with either a:
☒ Statement under 37 CFR 1.97 (e), or
☐ a \$180 fee under 37 CFR 1.17 (p); or
(After mailing of first Office Action, but prior to Notice of Allowance or Final

Office Action)

- ☐ under 37 CFR 1.97 (d) together with:
☐ Statement under 37 CFR 1.97 (e), and
☐ a \$180.00 fee set forth in 37 CFR 1.17 (p).

(Filed after final action or notice of allowance, whichever occurs first, but before payment of the issue fee)

☒ Applicant(s) submit herewith Form PTO 1449- Information Disclosure Citation together with copies of patents, publications or other information of which applicant(s) are aware, which applicant(s) believe(s) may be material to the examination of this application and for which there may be a duty to disclose in accordance with 37 CFR 1.56.

It is requested that the information disclosed herein be made of record in this application.

Any deficiency or overpayment should be charged or credited to deposit account number 13-1703. A duplicate copy of this sheet is enclosed.

Customer No. 20575

Respectfully submitted,

MARGER JOHNSON & McCOLLOM, P.C.



Hosoon Lee
Reg. No. 56,737

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For: ETCHING METHOD FOR MANUFACTURING
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Alexandria, VA 22313-1450STATEMENT ON FILING INFORMATION DISCLOSURE STATEMENT
(37 CFR 1.97(e))

I, Hosoon Lee, the person signing below state that:
each item of information contained in the Information Disclosure Statement submitted
herewith was first cited in a communication from a foreign patent office in a counterpart
foreign application not more than three months prior to the filing of this Statement

Applicant respectfully requests consideration of the accompanying Information
Disclosure Statement.

The person making this Statement is the attorney who signs below on the basis of the
information in the attorney's file.

Respectfully submitted,
MARGER JOHNSON & McCOLLOM, P.C.



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273-8300, on October 19, 2005.


Li Mei Vermilya

PATENT APPLICATION

Atty. Docket No.: 9898-314 Serial No. 10/850,864
Applicant: Won-Jun LEE, et al.
Filing Date: January 23, 2004 Group: 2812

INFORMATION DISCLOSURE CITATION
FORM PTO-1449 (Modified)U.S. PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Issue</u> <u>Date</u>	<u>Name</u>	<u>Class</u>	<u>Sub</u> <u>Class</u>
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FOREIGN PATENT DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Document</u> <u>Number</u>	<u>Publication</u> <u>Date</u>	<u>Country</u>	<u>Name</u>
_____	_____	2002-0083263	Nov. 2, 02	Korea	Hwang, et al.
_____	_____	2002-0090452	Dec. 5, 02	Korea	Ju, et al.

OTHER DOCUMENTS

<u>Exam</u> <u>Init</u>	<u>Ref</u>	<u>Author, Title, Date, Pertinent Pages, Etc.)</u>
_____	_____	English language abstract of Korean Publication No. 2002-0083263
_____	_____	English language abstract of Korean Publication No. 2002-0090452

Examiner: _____

Date Considered: _____